

(detailed derivation available in Supplemental Information):

$$\begin{aligned}
 F_{\omega_m}(t) &= \alpha' A \left\{ \left(V_{dc}^2 + \frac{V_{ac}^2}{2} \right) \cos(\omega_m t) + V_{dc} V_{ac} \cos(\omega_m t + \phi) \right\} \\
 &= \alpha' A \left\{ V_{dc}^2 + \cos(\phi) V_{dc} V_{ac} + \frac{V_{ac}^2}{2} \right\} \cos(\omega_m t) \\
 &\quad - \alpha' A V_{dc} V_{ac} \sin(\phi) \sin(\omega_m t) \\
 &= F_{in} \cos(\omega_m t) + F_{quad} \sin(\omega_m t)
 \end{aligned}$$

where

$$F_{in} = \alpha' A \left(V_{dc} + \frac{V_{ac}}{2} \cos \phi \right)^2 + \frac{\alpha' A}{2} \left(1 - \frac{\cos^2 \phi}{2} \right) V_{ac}^2 \quad (2)$$

$$F_{quad} = -\alpha' A V_{dc} V_{ac} \sin \phi \quad (3)$$

We notice that F_{quad} is proportional to α' rather than α , indicating F_{quad} is now sensitive to the electrostatic force gradient. It is interesting to notice that the apparent shift of V_{cpd} is just determined by ϕ and V_{ac} and does not depend on α in contrast to 1ω D-KPFM (See Eqs. 11-13 in Ref. [1]). A key aspect of this new technique is the absence of such a shift in F_{quad} for any ϕ , which is advantageous as it means that the accurate setting of ϕ is not required for accurate CPD measurements. ϕ just affects the magnitude of F_{quad} , which determines the signal-to-noise ratio of the CPD measurements. When $\phi = 90^\circ$, we obtain

$$F_{in} = \alpha' A \left(V_{dc} + \frac{V_{ac}}{2} \right) = \alpha' A (V_{bias} - V_{cpd})^2 + \frac{\alpha' A}{2} V_{ac}^2$$

$$F_{quad} = -\alpha' A V_{dc} V_{ac} = -\alpha' A (V_{bias} - V_{cpd}) V_{ac}$$

In this case, the apparent shift of CPD in F_{in} vanishes and the slope of $F_{quad} - (V_{bias} - V_{cpd})$ curve takes its maximum value. Notice that F_{quad} behaves exactly in the same way as the lock-in demodulated frequency shift signal used in FM-KPFM. When $V_{bias} = V_{cpd}$, the dissipation signal turns back to its original value, g_0 . It is therefore possible to use the dissipation signal, g , for the KPFM bias voltage feedback by choosing g_0 as its control setpoint value.

Figure 1 depicts the block diagram of the experimental setup used for both 1ω and 2ω D-KPFM measurements. The setup is based on the self-oscillation mode FM-AFM system [12] and three additional components, a frequency doubler, a phase shifter, a proportional-integrator (PI) controller, are required for D-KPFM operation. The amplitude controller composed of a root-mean-square (RMS) amplitude detector and a PI controller is used to keep an oscillation amplitude constant. The output of the amplitude controller is the dissipation signal which is used for controlling V_{bias} . The detection bandwidth of the RMS amplitude detector is extended to about 3 kHz. In order to produce a sinusoidal ac voltage with two times the tip oscillation frequency, the sinusoidal deflection signal from the cantilever deflection sensor is first fed into a frequency doubler. Then the output of the frequency doubler passes through

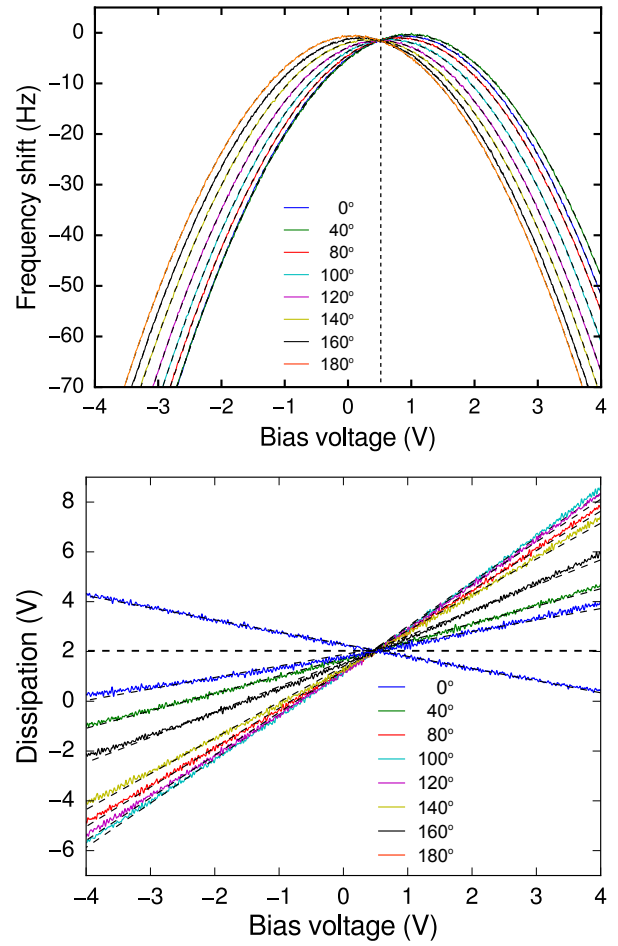


Figure 2. (a) Frequency shift, Δf , and (b) dissipation signal, g , versus dc bias voltage, V_{bias} , curves taken with a coherent sinusoidally oscillating voltage with $\omega_{el} = 2\omega_m$, $V_{ac} = 1$ V and various ϕ , applied to a template stripped gold substrate. The vertical dashed line in (a) indicates V_{cpd} which is measured as the voltage coordinate of the parabola vertex without V_{ac} . The horizontal dashed line in (b) indicates the dissipation without V_{ac} . In both figures, each of dashed lines represent fitted curves assuming a parabola for Δf and a linear line for g as indicated in Eq. 2 and 3, respectively. The oscillation amplitude of the tip was 10 nm_{p-p} and the quality factor of the cantilever was 25000.

the additional phase shifter (Phase Shifter 2), which serves to adjust the phase of the ac voltage, ϕ . The dissipation signal acts as the input signal to the PI controller, which adjusts V_{bias} to maintain a constant dissipation equal to the value without V_{ac} applied, g_0 [13].

We used a JEOL JSPM-5200 atomic force microscope for the experiments with the modifications described in Ref. [1]. An open source scanning probe microscopy control software GXSM was used for the control and data acquisition [14]. A commercial silicon AFM cantilever (NSC15, MikroMasch) with a typical spring constant of about 28 N/m and resonance frequency of ~ 300 kHz was used in high-vacuum environment with the pressure of 1×10^{-7} mbar.

In order to validate Eqs. 2 and 3, $\Delta f - V_{bias}$ and $g - V_{bias}$ curves

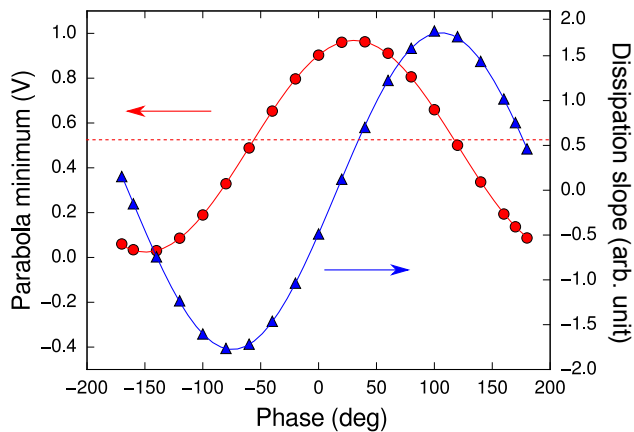


Figure 3. Voltage coordinate of the vertices of the measured Δf - V_{bias} curves (parabola minimum) (red circles) extracted from the results Fig. 2(a) and the slope of dissipation- V_{bias} curves (blue triangles) extracted from Fig. 2(b). Each solid line represents the fitted curve with the cosine function (Eq. 2) for the parabola minimum and with the sine function (Eq. 3) for the dissipation slope. The horizontal dashed line indicates the voltage coordinate of the parabola measured without the ac bias voltage.

were measured while a coherent sinusoidally oscillating voltage with $\omega_{\text{el}} = 2\omega_{\text{m}}$, $V_{\text{ac}} = 1 \text{ V}$ ($2 V_{\text{p-p}}$) and various phases, ϕ is superposed with V_{bias} . Figure 2(a) and (b) show simultaneously measured Δf and g versus V_{bias} curves, respectively. The curves are taken on a template stripped gold surface. A fitted curve with a parabola for each of the Δf - V_{bias} curves (Eq. 2) or with a linear line for each of the g - V_{bias} curves (Eq. 3) is overlaid on each experimental curve, indicating a very good agreement between the theory and experiments. As can be seen in Fig. 2(a) and (b), the position of the parabola vertex shifts both in V_{bias} and Δf axes and the slope of g - V_{bias} curve changes systematically with the varied phase, ϕ . For further validating the theory, the voltage coordinate of the parabola vertex (parabola minimum voltage) of each Δf - V_{bias} curve and the slope of each g - V_{bias} curve are plotted against ϕ in Fig. 3. Each plot is overlaid with a fitted curve (solid curve) with the cosine function (see Eq. 2) for the parabola minimum voltage and with the sine function (Eq. 3) for the dissipation slope, demonstrating an excellent agreement between the experiment and theory. The V_{bias} dependence of the frequency shift coordinate of the parabola vertices (frequency shift offset) also shows a very good agreement with the theory (second term of Eq. 2) (The fitting result is available in Supplemental Information). The parabola minimum voltage versus phase curve intersects that of Δf - V_{bias} without ac bias voltage at $\phi = 121^\circ$. The deviation from the theoretically predicted value of 90° is due to the phase delay in the detection electronics. We also notice that the amplitude of parabola minimum versus phase curve is 0.472 V which is in good agreement with 0.5 V predicted by the theory ($V_{\text{ac}}/2$ in Eq. 2).

Figure 4 shows CPD images of a patterned MoS_2 flake exfoliated on SiO_2/Si substrate taken by (a) 1ω D-KPFM,

(b) 2ω D-KPFM and (c) FM-KPFM techniques taken with the same tip. In 1ω (2ω) D-KPFM imaging, a sinusoidally oscillating voltage with $\omega_{\text{el}} = \omega_{\text{m}}$ ($\omega_{\text{el}} = 2\omega_{\text{m}}$), $V_{\text{ac}} = 50 \text{ mV}$ ($V_{\text{ac}} = 1 \text{ V}$) and $\phi = 22^\circ$ ($\phi = 18^\circ$) coherent with the tip oscillation was applied to the sample. In FM-KPFM imaging, a sinusoidally oscillating voltage with $\omega_{\text{el}} = 300 \text{ Hz}$ and $V_{\text{ac}} = 1 \text{ V}$ was applied to the sample. The detection bandwidth of the lock-in was 100 Hz . The scanning time for all the images were 1 s/line . A stripe pattern with $2 \mu\text{m}$ pitch was created by reactive ion etching on the MoS_2 flake. The topography images show an unetched terrace located between the etched regions (Image available in Supplemental Information.). The height of the unetched terrace is approximately 20 nm with respect to the etched regions. The bands shown in the middle of the CPD images corresponds to the unetched terrace and show a clear fractal-like pattern, which can be ascribed to the residue of the etch resist (PMMA). All three CPD images show apparently a very similar pattern on the terrace. However, a close inspection of the line profile of each image shows that 2ω D-KPFM and FM-KPFM provide a very similar potential profile with almost the same contrast while 1ω D-KPFM shows a potential contrast about two times smaller than that of 2ω D-KPFM and FM-KPFM. The close similarity between 2ω D-KPFM and FM-KPFM originates from the fact that F_{quad} (Eq. 3) is proportional to the force gradient as we have discussed above. Slightly larger potential contrast in 2ω D-KPFM compared with FM-KPFM is due to the faster feedback response of 2ω D-KPFM by virtue of the absence of low frequency modulation [1], which is a clear advantage of both D-KPFM techniques over FM-KPFM. The bandwidth of FM-KPFM is limited by detection bandwidth of the lock-in amplifier that needs to be lower than the frequency of the ac bias voltage. The lower contrast of 1ω D-KPFM is ascribed to its sensitivity to electrostatic force rather than electrostatic force gradient which results in larger spatial average due to the stray capacitance including the body of the tip and the cantilever [10, 15–18].

In spite of lower potential contrast, 1ω D-KPFM has an advantage that it requires much smaller $V_{\text{ac}} = 50 \text{ mV}$ compared with 1 V required in 2ω D-KPFM and FM-KPFM. This advantage is important for such samples as semiconductor where the influence of the large V_{ac} can be very important due to band-bending effects. As it is easy to switch between 1ω and 2ω D-KPFM modes, 1ω D-KPFM can be used for qualitative measurement with less electrical disturbance while 2ω D-KPFM can be used to obtain more accurate CPD contrast on the same sample location. Another advantage of 2ω D-KPFM is that it is free from the capacitive crosstalk to the piezoelectric element and photodiode signal line [19] as the frequency of the ac voltage itself does not match any resonance of the cantilever.

In conclusion, we report a new technique that enables force-gradient sensitive Kelvin probe force microscopy using the dissipation signal of FM-AFM for dc voltage feedback. It features the simpler implementation and faster scanning as it requires no low frequency modulation. The dissipation is caused by the oscillating electrostatic force that is coherent

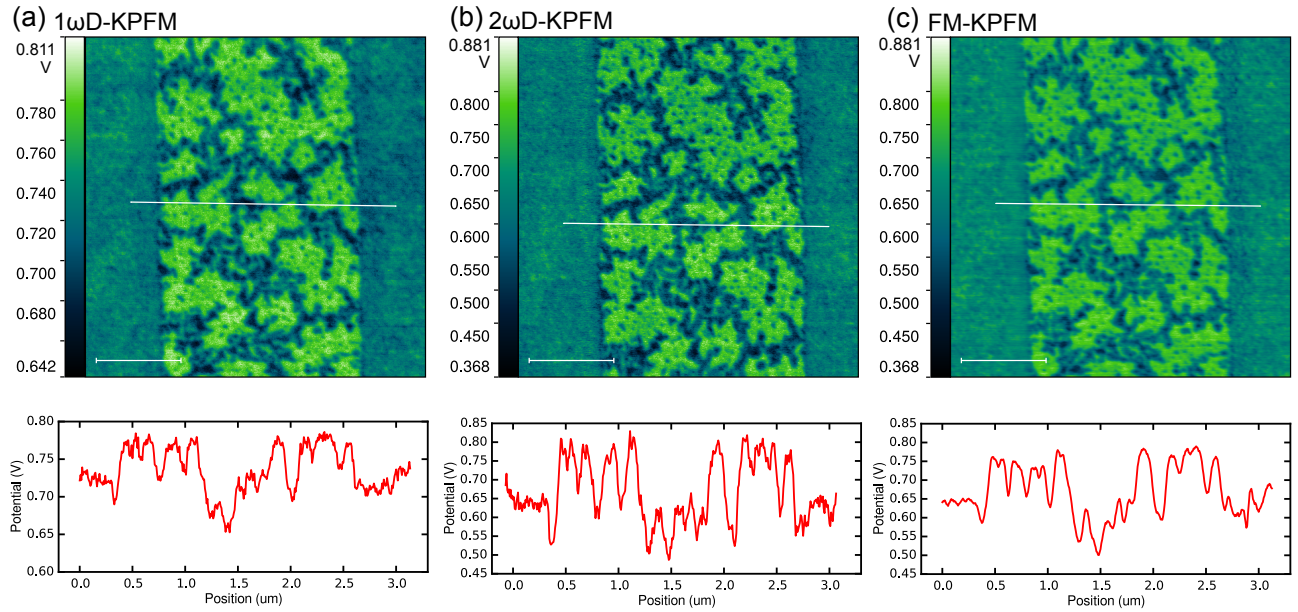


Figure 4. Potential images of patterned MoS_2 on SiO_2/Si substrate by (a) $1\omega\text{D-KPFM}$ ($\Delta f = -10.3$ Hz, $A = 5$ nm_{p-p}, $V_{\text{ac}} = 50$ mV), (b) $2\omega\text{D-KPFM}$ ($\Delta f = -8.3$ Hz, $A = 5$ nm_{p-p}, $V_{\text{ac}} = 1$ V) and (c) FM-KPFM ($\Delta f = -7.0$ Hz, $A = 5$ nm_{p-p}, $V_{\text{ac}} = 1$ V, $f_{\text{ac}} = 300$ Hz). Scale bar is $1\mu\text{m}$.

with the tip oscillation, which is induced by applying a sinusoidally oscillating ac voltage with the frequency two times that of the tip oscillation. We theoretically analyzed the effect of the applied ac voltage and show that the induced dissipation is sensitive to electrostatic force gradient rather than electrostatic force. The experiments confirmed the theoretical analysis and demonstrated that $2\omega\text{D-KPFM}$ provides essentially the same result obtained by FM-KPFM . The combination of 1ω and $2\omega\text{D-KPFM}$ techniques will be a versatile tool to study the samples whose electrical properties are sensitive to the external electric field.

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Supplemental information for
"Force-gradient sensitive Kelvin probe force microscopy by
dissipative electrostatic force modulation"

Yoichi Miyahara* and Peter Grutter

*Department of Physics, Faculty of Science,
McGill University, Montreal, Quebec, Canada H3A 2T8*

(Dated: March 2, 2022)

* Corresponding author: yoichi.miyahara@mcgill.ca

I. DERIVATION OF EQ. 2 AND 3

In the absence of localized charges, the electrostatic force between a conducting tip and sample under dc and ac bias voltage is described as follows:

$$F_{\text{elec}}(t) = \frac{1}{2} \frac{\partial C}{\partial z} \{V_{\text{bias}} + V_{\text{ac}} \cos(\omega_{\text{el}}t + \phi) - V_{\text{cpd}}\}^2 \quad (1)$$

$$= F_0 + F_{\omega} + F_{2\omega}$$

$$F_0 = \frac{1}{2} \frac{\partial C}{\partial z} \left[(V_{\text{bias}} - V_{\text{cpd}})^2 + \frac{V_{\text{ac}}^2}{2} \right] = \alpha \left(V_{\text{dc}}^2 + \frac{V_{\text{ac}}^2}{2} \right) \quad (2)$$

$$F_{\omega} = \frac{\partial C}{\partial z} (V_{\text{bias}} - V_{\text{cpd}}) V_{\text{ac}} \cos(\omega_{\text{el}}t + \phi) = 2\alpha V_{\text{dc}} V_{\text{ac}} \cos(\omega_{\text{el}}t + \phi) \quad (3)$$

$$F_{2\omega} = \frac{1}{4} \frac{\partial C}{\partial z} V_{\text{ac}}^2 \cos(2(\omega_{\text{el}}t + \phi)) = \frac{1}{2} \alpha V_{\text{ac}}^2 \cos(2(\omega_{\text{el}}t + \phi)) \quad (4)$$

where

$$\alpha \equiv \frac{1}{2} \frac{\partial C}{\partial z}, \quad V_{\text{dc}} \equiv V_{\text{bias}} - V_{\text{cpd}}$$

C : tip-sample capacitance

V_{bias} : applied dc bias voltage

V_{cpd} : contact potential difference

V_{ac} : amplitude of applied ac voltage

ω_{el} : angular frequency of applied ac voltage

ϕ : phase of applied ac voltage with respect to tip oscillation

z : position of the tip measured from the sample surface

In general, $\alpha \equiv \frac{1}{2} \frac{\partial C}{\partial z}(z(t))$ is also a function of time through time-dependent $z(t) = A \cos(\omega_{\text{m}}t)$ with ω_{m} and A being its oscillation angular frequency and amplitude, respectively.

By expanding α around the mean position z_0 , and taking the first order,

$$\alpha(z) \approx \alpha_0 + \alpha'(z - z_0) = \alpha_0 + \alpha' A \cos(\omega_{\text{m}}t) \quad (5)$$

Substituting α into eq.2 yields

$$\begin{aligned} F_0(t) &= \left\{ \alpha_0 + \alpha' A \cos(\omega_{\text{m}}t) \right\} \left(V_{\text{dc}}^2 + \frac{V_{\text{ac}}^2}{2} \right) \\ &= \alpha_0 \left(V_{\text{dc}}^2 + \frac{V_{\text{ac}}^2}{2} \right) + \alpha' A \left(V_{\text{dc}}^2 + \frac{V_{\text{ac}}^2}{2} \right) \cos(\omega_{\text{m}}t) \end{aligned} \quad (6)$$

The first term in the above formula yields the static deflection of the cantilever whereas the second one is an alternating force whose frequency is $\omega_{\text{m}}/2\pi$. As this force is in phase

with $z(t)$, it will lead to the shift in the resonance frequency.

Next, we look at F_ω term (eq. 3).

$$\begin{aligned}
F_\omega(t) &= 2\{\alpha_0 + \alpha' A \cos(\omega_m t)\} V_{dc} V_{ac} \cos(\omega_{el} t + \phi) \\
&= 2\alpha_0 V_{dc} V_{ac} \cos(\omega_{el} t + \phi) + 2\alpha' A V_{dc} V_{ac} \cos(\omega_{el} t + \phi) \cos(\omega_m t) \\
&= 2\alpha_0 V_{dc} V_{ac} \cos(\omega_{el} t + \phi) + 2\alpha' A V_{dc} V_{ac} \frac{1}{2} [\cos\{(\omega_{el} + \omega_m)t + \phi\} + \cos\{(\omega_{el} - \omega_m)t + \phi\}] \\
&= 2\alpha_0 V_{dc} V_{ac} \{\cos(\omega_{el} t) \cos(\phi) - \sin(\omega_{el} t) \sin(\phi)\} \\
&\quad + \alpha' A V_{dc} V_{ac} [\cos\{(\omega_{el} + \omega_m)t + \phi\} + \cos\{(\omega_{el} - \omega_m)t + \phi\}]
\end{aligned}$$

When $\omega_{el} = 2\omega_m$,

$$\begin{aligned}
F_\omega(t) &= 2\alpha_0 V_{dc} V_{ac} \{\cos(2\omega_m t) \cos(\phi) - \sin(2\omega_m t) \sin(\phi)\} \\
&\quad + \alpha' A V_{dc} V_{ac} [\cos\{(3\omega_m)t + \phi\} + \cos(\omega_m t + \phi)]
\end{aligned} \tag{7}$$

The only component that contributes to the frequency shift and dissipation is the last term in Eq. 7.

Looking at $F_{2\omega}$ term in the same way,

$$\begin{aligned}
F_{2\omega}(t) &= \frac{1}{2} \{\alpha_0 + \alpha' A \cos(\omega_m t)\} V_{ac}^2 \cos(2(\omega_{el} t + \phi)) \\
&= \frac{1}{2} [\alpha_0 V_{ac}^2 \cos(2(\omega_{el} t + \phi)) + \frac{1}{2} \alpha' A V_{ac}^2 \{\cos\{(2\omega_{el} - \omega_m)t + 2\phi\} + \cos\{(2\omega_{el} + \omega_m)t + 2\phi\}\}] \\
&= \frac{1}{2} \alpha_0 V_{ac}^2 \cos(2(\omega_{el} t + \phi)) + \frac{1}{4} \alpha' A V_{ac}^2 \{\cos((2\omega_{el} - \omega_m)t + 2\phi) + \cos((2\omega_{el} + \omega_m)t + 2\phi)\} \\
&= \frac{1}{2} \alpha_0 V_{ac}^2 \cos(4\omega_m t + 2\phi) + \frac{1}{4} \alpha' A V_{ac}^2 \{\cos(3\omega_m t + 2\phi) + \cos(5\omega_m t + 2\phi)\}
\end{aligned} \tag{8}$$

No term in Eq. 8 contributes to the frequency shift and dissipation.

Gathering the terms with ω_m from Eq. 6 and 8, we obtain the following result shown in Eq 2 and 3 in the body text.

$$\begin{aligned}
F_{\omega_m}(t) &= \alpha' A \left\{ \left(V_{dc}^2 + \frac{V_{ac}^2}{2} \right) \cos(\omega_m t) + V_{dc} V_{ac} \cos(\omega_m t + \phi) \right\} \\
&= \alpha' A \left\{ V_{dc}^2 + \cos(\phi) V_{dc} V_{ac} + \frac{V_{ac}^2}{2} \right\} \cos(\omega_m t) \\
&\quad - \alpha' A V_{dc} V_{ac} \sin(\phi) \sin(\omega_m t) \\
&= F_{in} \cos(\omega_m t) + F_{quad} \sin(\omega_m t)
\end{aligned}$$

where

$$F_{\text{in}} = \alpha' A \left(V_{\text{dc}} + \frac{V_{\text{ac}}}{2} \cos \phi \right)^2 + \frac{\alpha' A}{2} \left(1 - \frac{\cos^2 \phi}{2} \right) V_{\text{ac}}^2 \quad (9)$$

$$F_{\text{quad}} = -\alpha' A V_{\text{dc}} V_{\text{ac}} \sin \phi \quad (10)$$

II. FITTING RESULT OF FREQUENCY SHIFT OFFSET AS A FUNCTION OF PHASE

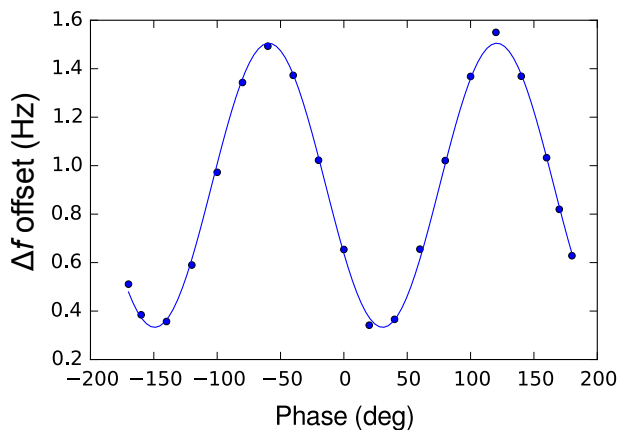


FIG. 1. Frequency shift offset as a function of phase. Solid line is the fitted curve with the second term of Eq. 2 in the body text.

III. DETAIL OF THE SAMPLE

A. Optical micrograph of MoS₂ flakes

B. AFM topography images of MoS₂ flake

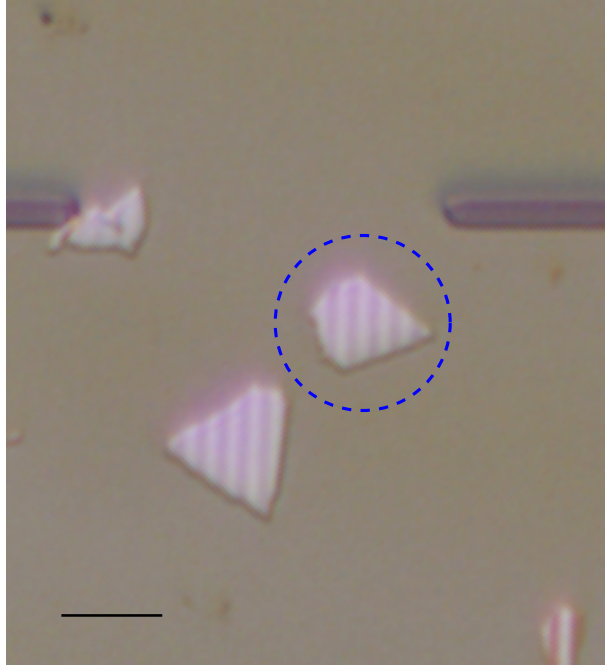


FIG. 2. Optical micrograph of the MoS₂ flakes exfoliated on SiO₂/Si substrate. The flake in the circle is the one imaged by KPFM. Scale bar is 20 μm .

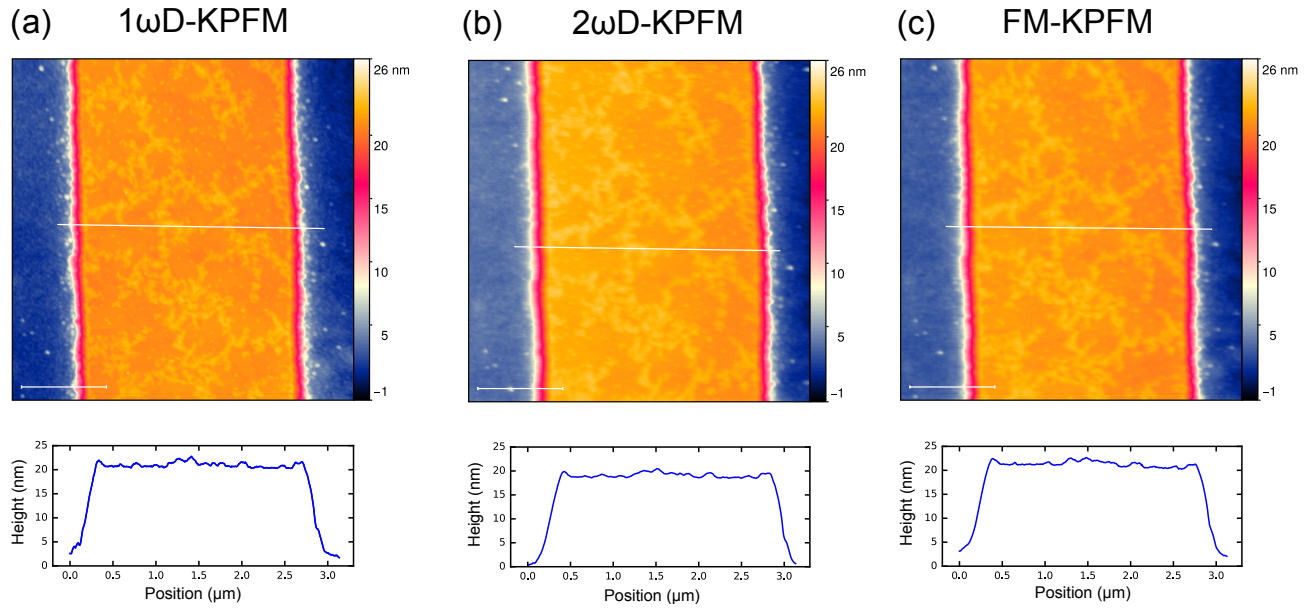


FIG. 3. Topography images of patterned MoS_2 on SiO_2/Si substrate simultaneously taken with each corresponding KPFM image shown in Fig. 4 in the body text. (a) D-KPFM (1ω) ($\Delta f = -10.3$ Hz, $A = 5$ nm_{p-p}, $V_{\text{ac}} = 50$ mV) and (b) D-KPFM (2ω) ($\Delta f = -8.3$ Hz, $A = 5$ nm_{p-p}, $V_{\text{ac}} = 1$ V) and (c) FM-KPFM ($\Delta f = -7.0$ Hz, $A = 5$ nm_{p-p}, $V_{\text{ac}} = 1$ V). The line profiles are shown for the same location on the sample.